

4V Drive Pch + Pch MOSFET

QS8J5

Structure

Silicon P-channel MOSFET

Features

1) Low on-resistance.

- 2) High power package(TSMT8).
- 3) Low voltage drive(4V drive).

Application

Switching

Packaging specifications

	Package	Taping
Туре	Code	TR
	Basic ordering unit (pieces)	3000
QS8J5		0

• Absolute maximum ratings (Ta = 25°C)

	Tailige (Ta Lo	0)			
Parameter		Symbol	Limits	Unit	
Drain-source voltage		V _{DSS}	-30	V	
Gate-source voltage		V _{GSS}	±20	V	
Drain current	Continuous	I _D	±5	А	
		ا _{DP} 1	±20	А	
Source current	Continuous	l _s	-1	А	
(Body Diode)	Pulsed	^{*1} ا	-20	А	
Power dissipation		P _D *2	1.5	W / TOTAL	
		· D -	1.25	W / ELEMENT	
Channel temperature		Tch	150	°C	
Range of storage temp	erature	Tstg	-55 to +150	°C	

*1 Pw≤10μs, Duty cycle≤1%

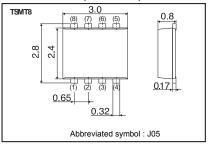
*2 Each terminal mounted on a ceramic board.

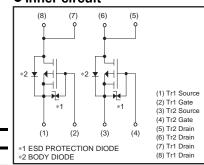
Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to ambient	Rth (ch-a)	83.3	°C / W /TOTAL
	Rui (cii-a)	100	°C / W /ELEMENT

* Each terminal mounted on a ceramic board.

• Dimensions (Unit : mm)





Inner circuit

• Electrical characteristics (Ta = 25°C)

<It is the same ratings for Tr1 and Tr2.>

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Gate-source leakage	I _{GSS}	-	-	±10	μA	V _{GS} =±20V, V _{DS} =0V
Drain-source breakdown voltage	V _{(BR)DSS}	-30	-	-	V	I _D =–1mA, V _{GS} =0V
Zero gate voltage drain current	I _{DSS}	-	-	-1	μA	V _{DS} =-30V, V _{GS} =0V
Gate threshold voltage	V _{GS (th)}	-1.0	-	-2.5	V	V_{DS} =-10V, I_{D} =-1mA
	*	-	28	39		I _D =–5A, V _{GS} =–10V
Static drain-source on-state resistance	R _{DS (on)}	-	40	56	mΩ	I _D =-2.5A, V _{GS} =-4.5V
		-	45	63		I _D =-2.5A, V _{GS} =-4V
Forward transfer admittance	۱ Y _{fs} ľ*	3	-	-	S	I _D =–5A, V _{DS} =–10V
Input capacitance	C _{iss}	-	1100	-	pF	V _{DS} =-10V
Output capacitance	C _{oss}	-	150	-	pF	V _{GS} =0V
Reverse transfer capacitance	C _{rss}	-	130	-	pF	f=1MHz
Turn-on delay time	t _{d(on)} *	-	9	-	ns	I _D =–2.5A, V _{DD} ≒–15V
Rise time	t _r *	-	40	-	ns	V _{GS} =–10V
Turn-off delay time	t _{d(off)} *	-	90	-	ns	R _L ≒6Ω
Fall time	t _f *	-	55	-	ns	R_G =10 Ω
Total gate charge	Q _g *	-	10.0	-	nC	I _D =–5A, V _{DD} ≒−15V
Gate-source charge	Q _{gs} *	-	3.6	-	nC	V _{GS} =–5V
Gate-drain charge	Q _{gd} *	-	3.0	-	nC	R _L ≒3Ω, R _G =10Ω

*Pulsed

•Body diode characteristics (Source-Drain) (Ta = 25°C)

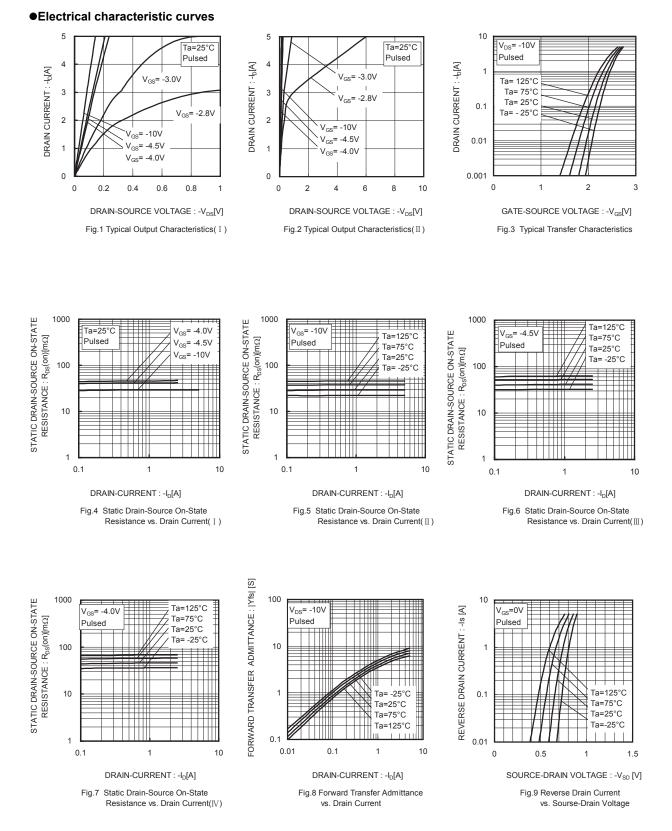
<It is the same ratings for Tr1 and Tr2.>

Forward voltage V_{SD}^* 1.2 V I_s =-5A, V_{GS} =0	Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
	Forward voltage	V_{SD}^{*}	-	-	-17	V	I _s =–5A, V _{GS} =0V

*Pulsed

Data Sheet

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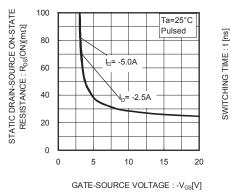
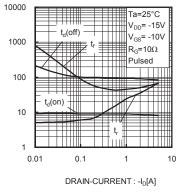
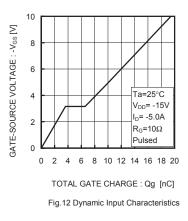
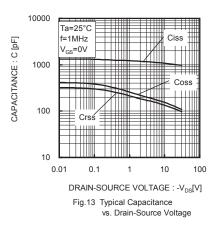


Fig.10 Static Drain-Source On-State Resistance vs. Gate Source Voltage









Measurement circuits

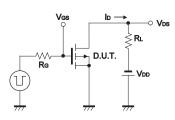


Fig.1-1 Switching Time Measurement Circuit

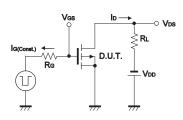


Fig.2-1 Gate Charge Measurement Circuit

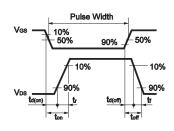


Fig.1-2 Switching Waveforms

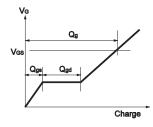


Fig.2-2 Gate Charge Waveform

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